NSN 5961-01-518-9377

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-518-9377 **Inclosure Material:** Plastic **Overall Length:** Between 0.188 inches and 0.197 inches **Overall Height:** Between 0.053 inches and 0.069 inches **Overall Width:** Between 0.228 inches and 0.244 inches **Function For Which Designed:** Transient suppressor Joint Electronic Device Engineering Council/jedec/case Outline Designation: So-8 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 12.0 working peak reverse voltage **Current Rating Per Characteristic:** 12.00 amperes all primaries universal **Power Rating Per Characteristic:** 300.0 watts forward power dissipation, dc pascal **Capacitance Rating In Picofarads:** 5.0 **Terminal Type And Quantity:** 8 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: